L	Hits	Search Text	DB	Time stamp
Number 2	20	((bipolar adj transistor) and (base with	USPAT;	2004/08/08
2	20	((silicon Si)and ((silicon adj germanium)	US-PGPUB	14:16
		sige si-ge)) same depletion)) not		
		((bipolar adj transistor) and (base with ((silicon Si)and ((silicon adj germanium)		
		sige si-ge)) with depletion))		
3	19	(bipolar adj transistor) and (base with	USPAT;	2004/08/08
		((silicon Si)and ((silicon adj germanium)	US-PGPUB	13:34
4	39	sige si-ge)) with depletion) (((bipolar adj transistor) and (base with	USPAT;	2004/08/08
]]]	((silicon Si) and ((silicon adj germanium)	US-PGPUB	13:34
		sige si-ge)) same depletion)) not		
		((bipolar adj transistor) and (base with		
		((silicon Si)and ((silicon adj germanium) sige si-ge)) with depletion))) or		
		((bipolar adj transistor) and (base with		
		((silicon Si)and ((silicon adj germanium)		
		sige si-ge)) with depletion))		
1	166	(bipolar adj transistor) and ((non-saturated nonsaturated ((non "not")	USPAT; US-PGPUB	2004/08/08 14:32
		adj saturated)))	05-FGEOD	17.32
5	33	((bipolar adj transistor) and	USPAT;	2004/08/08
		((non-saturated nonsaturated ((non "not")	US-PGPUB	14:10
		adj saturated)))) and (438/\$.ccls. or 257/\$.ccls.)		
6	7	· · · · · · · · · · · · · · · · · · ·	USPAT;	2004/08/08
		((non-saturated nonsaturated ((non "not")	US-PGPUB	13:59
		adj saturated)))) and (438/\$.ccls. or		
7	2	257/\$.ccls.)) and (depletion) (("6762106") or ("5484737")).PN.	USPAT;	2004/08/08
'		(6/62106) Of (5464/3/)).PN.	US-PGPUB	14:10
8	О	((("6762106") or ("5484737")).PN.) and	USPAT;	2004/08/08
		deplet\$	US-PGPUB	14:15
9	0	((("6762106") or ("5484737")).PN.) and	USPAT;	2004/08/08
,	Ĭ	breakdown	US-PGPUB	14:15
10	0		USPAT; US-PGPUB	2004/08/08
		boltage	US-PGPUB	14:15
11	1	((("6762106") or ("5484737")).PN.) and	USPAT;	2004/08/08
		voltage	US-PGPUB	14:15
12	1	((("6762106") or ("5484737")).PN.) and	USPAT;	2004/08/08
12	_	voltage	US-PGPUB	14:15
13	192		USPAT;	2004/08/08
14	0	thickness with breakdown)) (((bipolar adj transistor) and (base with	US-PGPUB USPAT;	16:20 2004/08/08
		thickness with breakdown))) not basis	US-PGPUB	14:32
15	0	(((1	USPAT;	2004/08/08
17	0	thickness with breakdown))) not "basis" ((bipolar adj transistor) and	US-PGPUB USPAT;	14:32 2004/08/08
• ′		<pre>((b)polar adj transistor; and ((non-saturated nonsaturated ((non "not"))</pre>	USPAT; US-PGPUB	14:32
		adj saturated)))) and (((bipolar adj		
		transistor) and (base with thickness with		
16	139	breakdown))) not "basis") (((bipolar adj transistor) and (base with	USPAT;	2004/08/08
10	139	thickness with breakdown)) not "basis"	USPAT; US-PGPUB	16:19
18	42	((((bipolar adj transistor) and (base	USPAT;	2004/08/08
	ĺ	with thickness with breakdown))) not	US-PGPUB	14:34
19	1	"basis") and (thickness near2 base) ("5484737").PN.	USPAT;	2004/08/08
		(0.03/0/ /.IM.	US-PGPUB	15:24
20	0	(("5484737").PN.) and (mis misfet)	USPAT;	2004/08/08
21		//UEA04727U\ DN \ =================================	US-PGPUB	15:24
21	0	(("5484737").PN.) and (mis misfet)	USPAT; US-PGPUB	2004/08/08 15:30
22	1	(("5484737").PN.) and (transistor)	USPAT;	2004/08/08
	L	, , , , , , , , , , , , , , , , , , , ,	US-PGPUB	15:24

23	0	(("5484737").PN.) and (heterojunction)	USPAT;	2004/08/08
			US-PGPUB	15:30
25	300	bipolar with mis	USPAT;	2004/08/08
	1	·· ··- ·	US-PGPUB	15:52
26	16	(bipolar with (misfet mis)) same	USPAT;	2004/08/08
] 20		advantage	US-PGPUB	15:53
2.7	١,	1		
27	4	((bipolar adj transistor) and (base with	USPAT;	2004/08/08
1	_	thickness with breakdown with optimiz\$))	US-PGPUB	16:22
28	7	((bipolar adj transistor) and (base with	USPAT;	2004/08/08
		thickness with optimiz\$) same breakdown)	US-PGPUB	16:29
29	5	(((bipolar adj transistor) and (base with	USPAT;	2004/08/08
		thickness) same optimiz\$) same breakdown)	US-PGPUB	16:30
30	14	((bipolar adj transistor) and ((base with	USPAT;	2004/08/08
"		thickness) same optimiz\$) same breakdown)	US-PGPUB	16:30
31	7	(((bipolar adj transistor) and ((base	USPAT;	2004/08/08
31			US-PGPUB	16:31
		with thickness) same optimiz\$) same	05-PGP0B	16:31
		breakdown)) not (((bipolar adj		
		transistor) and (base with thickness with		
		optimiz\$) same breakdown))		
32	136	((((bipolar adj transistor) and (base	USPAT;	2004/08/08
		with thickness with breakdown))) not	US-PGPUB	16:33
		"basis") not (@ad>20030812 or		
		@rlad>20030812)		j l
33	128	((((bipolar adj transistor) and (base	USPAT;	2004/08/08
1		with thickness with breakdown))) not	US-PGPUB	16:33
		"basis") not (@ad>20020815 or	22 13100	10.55
		@rlad>20020815)		
-] 3	(("5323032") or ("5323031") or	USPAT;	2004/08/07
		("6365479")).PN.	US-PGPUB	14:24
-	34006	bipolar adj transistor	USPAT;	2004/08/07
	İ		US-PGPUB	14:24
-	406	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
		(silicon and (silicon adj germanium)))	US-PGPUB	18:33
_	92	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
		(silicon and (silicon adj germanium))	US-PGPUB	18:41
		with (two second))	05 10105	1 20.12
1_	102	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
	102		1	
		(silicon and (silicon adj germanium))	US-PGPUB	18:13
	1	with (two second double stacked))		/
-	177	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
		(silicon and (silicon adj germanium) (si	US-PGPUB	15:30
		and sige)) with (two second double		
	1	stacked))		
-	82	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
	1	("si/sige"))	US-PGPUB	15:56
I -	8	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
1	1	("si/sige/si"))	US-PGPUB	16:06
I -	1	("5798277").PN.	USPAT;	2004/08/07
1	1	,	US-PGPUB	15:30
1_	1	//"5799277"\ DN \ and amittan		
1	1	(("5798277").PN.) and emitter	USPAT;	2004/08/07
1	1	Made and the second sec	US-PGPUB	15:31
1 -	84	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
1	1	("si/sige")) or (base with ("si/si-ge"))	US-PGPUB	15:57
-	82	((bipolar adj transistor) and (base with	USPAT;	2004/08/07
1		("si/sige")) or (base with ("si/si-ge")))	US-PGPUB	19:04
1	1	not (@ad>20030812 or @rlad>20030812)		1
-	1	(bipolar adj transistor) and (base with	USPAT;	2004/08/07
I	1	("si/si-ge/si"))	US-PGPUB	16:46
-	7		USPAT	2004/08/07
1	'	"5440152" "5719415" "5798539"		16:27
1	t	"6031256").PN.		1
1_	1		IICDam -	2004/00/07
1	. 1	09/252908	USPAT;	2004/08/07
		//hd-1-1	US-PGPUB	16:46
ļ -	98	(, 1	USPAT;	2004/08/07
		(silicon and (silicon adj germanium))	US-PGPUB	17:07
		with (two second double stacked))) not		
		((bipolar adj transistor) and (base with		
		("si/sige")) or (base with ("si/si-ge")))		

97 (((bipolar adj transistor) and (base with (silicon ad) (silicon a					
with (two second double stacked)) not ((bipolar ad) transistor) and (base with ("si/sige")) or (base with (silicon Si) and (silicon ad) germanium) sige si-ge)) 10/638401 and depletion	-	97	(((bipolar adj transistor) and (base with	USPAT;	2004/08/08
with (two second double stacked)) not ((bipolar ad) transistor) and (base with ("si/sige")) or (base with (silicon Si) and (silicon ad) germanium) sige si-ge)) 10/638401 and depletion				US-PGPUB	16:33
((bipolar adj transistor) and (base with ("si/sig"))) or (base with ("si/sig")))) or (base with ("si/sig")) or (base with ("si/sig"))) or (base with (silicon si) and (silicon adj germanium) sige si-ge)) with depletion) - 19 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion) - 19 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion) - 20 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) - 21 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge) same depletion) - 22 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge) same depletion)) not (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion)) not (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion)) not (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same septembre second double stacked))) not (sad>20030812 or (srlaton) same second double stacked))) not (sad>20030812 or (srlaton) same second same second sa					
("si/sige")) or (base with ("si/sige")) not (@ad>20030812 or @rlad>20030812)					
("si/si-ge"))) not (@ad>20030812 or endad>20030812)					1
Part					
1					
1	_	1		IISDAT.	2004/08/07
- 0 ((""6346452").PN.) and emitter		_	(0540452).FN.		1
1 10/638401 17:50 2004/08/07 18:13 2004/08/07 18:13 2004/08/07 18:13 2004/08/07 18:13 2004/08/07 18:13 2004/08/07 18:13 2004/08/07 18:13 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/08 2	_		//UC2464E2U\ DN \ and amithton		
1 10/638401	-	"	(("6346452").PN.) and emitter	1	1
1 10/638401 and depletion 1 10/638401 and depletion 2004/08/07 105-PGPUB 118:13 2004/08/07 119 (bipolar adj transistor) and (base with (silicon Si)and ((silicon adj germanium) sige si-ge)) with depletion) 20 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) 20 ((bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) 20 ((bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion) 1 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion)) 1 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same ((non-saturated nonsaturated ((non "not") adj saturated)))) 2 ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) sige si-ge)) same ((non-saturated))) 3 ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not (bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (silicon and (silicon adj germanium) sige si-ge) same ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) sige si-ge) same ((non-saturated))) 3 ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) 4 ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)			10/620403	l	
- 1 10/638401 and depletion	_	1	10/638401	I	The state of the s
(silicon Si) and ((silicon adj germanium) sige si-ge)) (bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) with depletion) (bipolar adj transistor) and (base with ((silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) (bipolar adj transistor) and (base with ((silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) ((bipolar adj transistor) and (base with ((silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) (bipolar adj transistor) and (base with ((silicon Si) and (silicon adj germanium) sige si-ge)) with depletion) (bipolar adj transistor) and (base with ((silicon Si) and (silicon adj germanium) sige si-ge)) with depletion) (bipolar adj transistor) and (base with (silicon adj germanium) sige si-ge)) with depletion) (bipolar adj transistor) and (base with (silicon adj germanium) (silicon adj g		_		–	
Separation Sep	-	1	10/638401 and depletion	I	2004/08/07
((silicon Si) and ((silicon ad) germanium) sige si-ge)) (bipolar ad) transistor) and (base with ((silicon Si) and ((silicon ad) germanium) sige si-ge)) with depletion) (Uspat; Us-PGPUB 13:34 2004/08/08 13:34 2004/08/08 13:34 2004/08/08 13:34 2004/08/08 13:34 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/07 2004/08/08 2004/08/07 2004/08/08 2004/08/07 2004/08/08 20				US-PGPUB	al .
Sige si-ge) (bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) with depletion) 39 (bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) same depletion) 10 ((bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) same depletion)) not ((bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) same depletion)) not ((bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) with depletion)) 1		689		USPAT;	2004/08/07
19 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion) 39 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion) 20 ((bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) same depletion)) not ((bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion)) 1 (bipolar adj transistor) and (base with (silicon Si) and (silicon adj germanium) sige si-ge)) with depletion)) 20 ((silicon Si) and (silicon adj germanium) sige si-ge)) with depletion)) 3 ((bipolar adj transistor) and (base with (silicon si) and (silicon adj germanium) sige si-ge)) same (non-saturated nonsaturated (non "not") adj saturated))) (((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not (bipolar adj transistor) and (base with (silicon adj germanium) (si and sige)) with (two second double stacked))) not (bipolar adj transistor) and (base with (silicon adj germanium)) with (two second double stacked))) not (bipolar adj transistor) and (base with (silicon adj germanium) (silicon adj germanium)) with (two second double stacked))) not (bipolar adj transistor) and (base with (silicon adj germanium) (silicon adj germanium) (silicon adj germanium) (silicon adj germanium) (silico			((silicon Si)and ((silicon adj germanium)	US-PGPUB	18:34
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sige si-ge)) with depletion) (bipolar adj transistor) and (base with ((silicon Si)and ((silicon adj germanium) sige si-ge)) same depletion) ((bipolar adj transistor) and (base with ((silicon Si)and ((silicon adj germanium) sige si-ge)) same depletion)) not ((bipolar adj transistor) and (base with ((silicon Si)and ((silicon adj germanium) sige si-ge)) with depletion)) (bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) with depletion)) (bipolar adj transistor) and (base with ((silicon Si) and ((silicon adj germanium) sige si-ge)) same ((non-saturated nonsaturated ((non "not") adj saturated)))) ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((Bad>20030812) reflad>20030812) 151 (((bipolar adj transistor) and (base with (silicon adj germanium) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium)) with (two second double stacked))) not ((Bipolar adj transistor) and (base with (silicon adj germanium)) with (two second double stacked))) not ((Bipo					
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stacked))) (((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812) 51 ((((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					
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<pre>(silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812) (((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not</pre>	-	73		USPAT:	2004/08/07
and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812) ((((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not			(silicon and (silicon adi germanium) (si	•	
stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not (@ad>20030812 or @rlad>20030812) ((((bipolar adj transistor) and (base with (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					
and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not (@ad>20030812 or @rlad>20030812) ((((bipolar adj transistor) and (base with (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not	[
germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812) 51 ((((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					l i
stacked)))) not (@ad>20030812 or @rlad>20030812) ((((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					
Grlad>20030812) ((((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not		Ì	stacked)))) not (@ad>20030812 or		
((((bipolar adj transistor) and (base with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					
<pre>with (silicon and (silicon adj germanium) (si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not</pre>	_	E1		IICDAM -	2004/00/07
<pre>(si and sige)) with (two second double stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not</pre>		21	((())) and (pase) (())	· · · ·	
stacked))) not ((bipolar adj transistor) and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not			with (Silicon and (Silicon adj germanium)	US-PGPUB	19:04
and (base with (silicon and (silicon adj germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not]		(SI and Sige)) with (TWO second double		j i
<pre>germanium)) with (two second double stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not</pre>					
stacked)))) not (@ad>20030812 or @rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					Į
<pre>@rlad>20030812)) not (((bipolar adj transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not</pre>					
transistor) and (base with ("si/sige")) or (base with ("si/si-ge"))) not					
or (base with ("si/si-ge"))) not		ľ	@rlad>20030812)) not (((bipolar adj]
(@ad>20030812 or @rlad>20030812))					

-	51	1 (((((((((((((((((((USPAT;	2004/08/07
		with (silicon and (silicon adj germanium)	US-PGPUB	19:11
		(si and sige)) with (two second double		
		stacked))) not ((bipolar adj transistor)		
		and (base with (silicon and (silicon adj		
		germanium)) with (two second double		
		stacked)))) not (@ad>20030812 or		
		@rlad>20030812)) not (((bipolar adj		
		transistor) and (base with ("si/sige"))		
		or (base with ("si/si-ge"))) not		
		(@ad>20030812 or @rlad>20030812))) not		
		((bipolar adj transistor) and (base with		
		("si/sige/si")))		
-	3	hirofumi near kawai	USPAT;	2004/08/07
	I		US-PGPUB	19:11